IN THE CLAIMS

Claims 1-64 are canceled.

65. [Previously Presented] A field emission display method comprising: providing a monolithic semiconductive substrate;

providing a luminescent member spaced from and opposite the monolithic semiconductive substrate;

forming a plurality of emitter regions using the monolithic semiconductive substrate;

electrically isolating the plurality of emitter regions from one another;

providing a plurality of emitters within individual ones of the emitter regions;

providing a plurality of address circuits for respective ones of the emitter regions and individually comprising row circuitry and column circuitry;

coupling individual ones of the address circuits with emitters of respective individual ones of the emitter regions;

using the respective address circuits, providing an electrical potential across selected ones of the emitters of the respective emitter regions; and

responsive to the electrical potential, emitting electrons from the selected emitters towards the luminescent member to generate an image.

66. [Previously Presented] The method of claim 65 wherein the providing the electrical potential comprises applying the electrical potential across different elevational portions of the selected emitters of the respective emitter regions.

67. [Previously Presented] The method of claim 65 further comprising:

providing a vacuum intermediate the monolithic semiconductive substrate and the luminescent member; and

passing the electrons through the vacuum towards the luminescent member after the emitting.

- 68. [Previously Presented] The method of claim 65 wherein the electrically isolating comprises etching the monolithic semiconductive substrate to define the emitter regions.
- 69. [Previously Presented] The method of claim 65 wherein the providing the emitters comprises forming the plurality of emitters to comprise bulk substrate material of the monolithic semiconductive substrate.
- 70. [Previously Presented] The method of claim 65 wherein the luminescent member comprises a face plate.
- 71. [Previously Presented] The method of claim 65 wherein the luminescent member comprises a phosphor material configured to generate the image responsive to the reception of the electrons.

Appl. No. 09/251,172 Amdt. dated February 28, 2005 Reply to Office Action dated 10/28/2004

72. [Previously Presented] The method of claim 65 wherein the address

circuits are individually configured to address the emitters of individual ones of the

respective emitter regions independent of others of the address circuits.

73. [Previously Presented] The method of claim 65 wherein the providing the

emitters comprises etching bulk semiconductive material of the monolithic

semiconductive substrate.

74. [Previously Presented] The method of claim 65 wherein the row circuitry

and the column circuitry of an individual one of the address circuits comprise a plurality

of address lines arranged orthogonal with respect to one another within the respective

one of the emitter regions.

75. [Previously Presented] The method of claim 65 wherein the coupling of

the address circuits with the emitters of the respective emitter regions comprises

configuring individual ones of the address circuits to address the emitters of the

respective emitter region independent of addressing of the emitters of others of the

emitter regions using others of the address circuits.

Claims 76-110 are canceled.

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Appl. No. 09/251,172 Amdt. dated February 28, 2005 Reply to Office Action dated 10/28/2004

111. [New] The method of claim 65 wherein the providing the emitters comprises forming the emitters within the emitter regions to comprise material of the

monolithic semiconductive substrate.

112. [New] The method of claim 65 wherein the providing the address circuits comprises providing the address circuits comprising circuitry external of the monolithic semiconductive substrate.